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[SANYO Semiconductor \(U.S.A\) Corporation](#)
[ECH8411-TL-E](#)

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Ordering number : ENA0073



SANYO Semiconductors

DATA SHEET

N-Channel Silicon MOSFET

ECH8411 — General-Purpose Switching Device Applications

Features

- Ultrahigh-speed switching.
- 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	V _{GSS}		±12	V
Drain Current (DC)	I _D		9	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	36	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm²×0.8mm)	1.4	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0V	20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	0.5		1.3	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =4A	7	12		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =4A, V _{GS} =4V		12	16	mΩ
	R _{DS(on)2}	I _D =2A, V _{GS} =2.5V		16	23	mΩ
	R _{DS(on)3}	I _D =2A, V _{GS} =1.8V		25	36	mΩ
Input Capacitance	C _{iss}	V _{DS} =10V, f=1MHz		1740		pF
Output Capacitance	C _{oss}	V _{DS} =10V, f=1MHz		310		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =10V, f=1MHz		290		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		30		ns
Rise Time	t _r	See specified Test Circuit.		170		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		240		ns
Fall Time	t _f	See specified Test Circuit.		210		ns

Marking : KR

Continued on next page.

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ECH8411

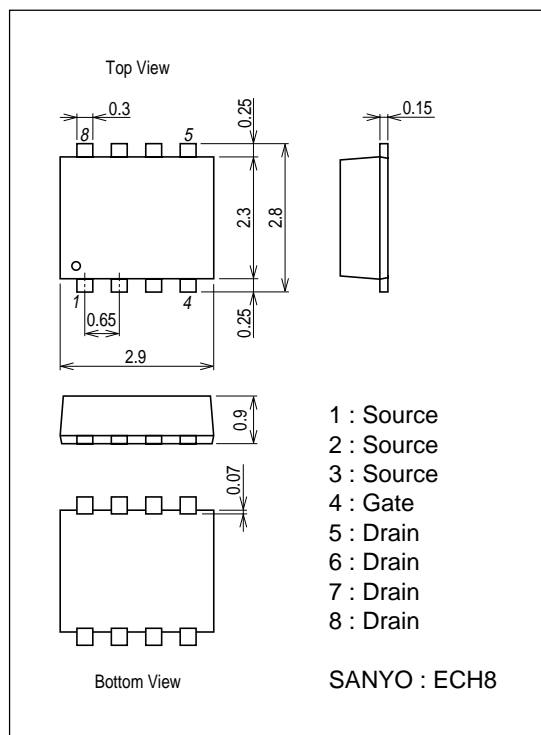
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	$V_{DS}=10V, V_{GS}=4V, I_D=9A$		21		nC
Gate-to-Source Charge	Qgs	$V_{DS}=10V, V_{GS}=4V, I_D=9A$		3.5		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=10V, V_{GS}=4V, I_D=9A$		6.2		nC
Diode Forward Voltage	V_{SD}	$I_S=9A, V_{GS}=0V$		0.84	1.2	V

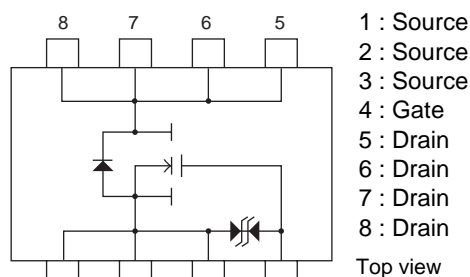
Package Dimensions

unit : mm

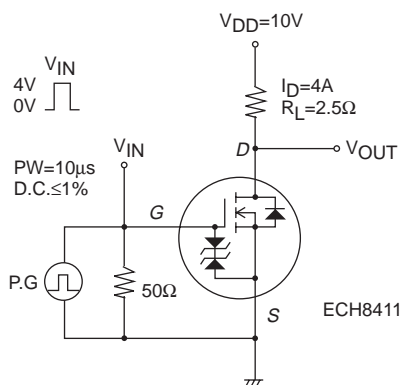
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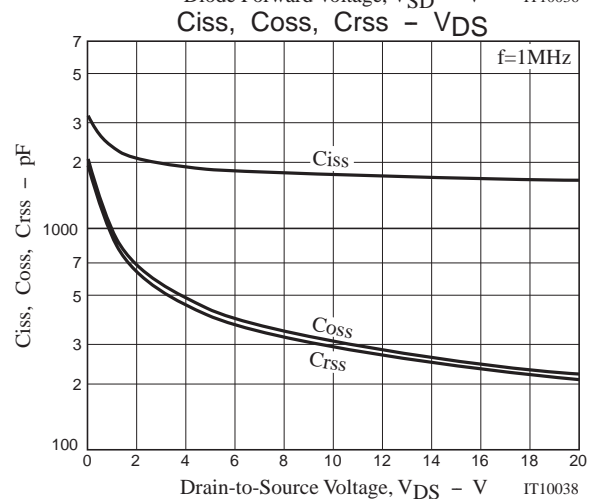
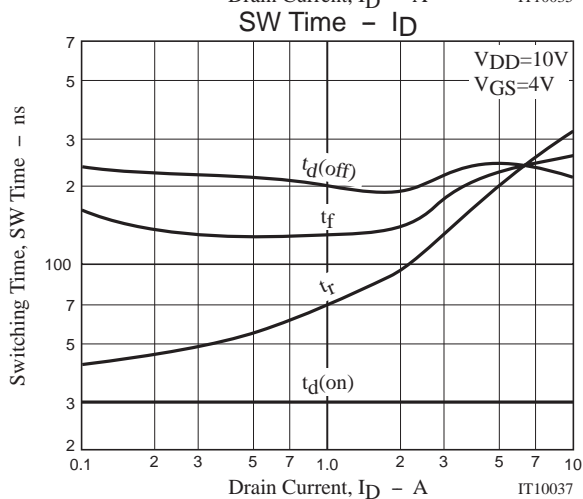
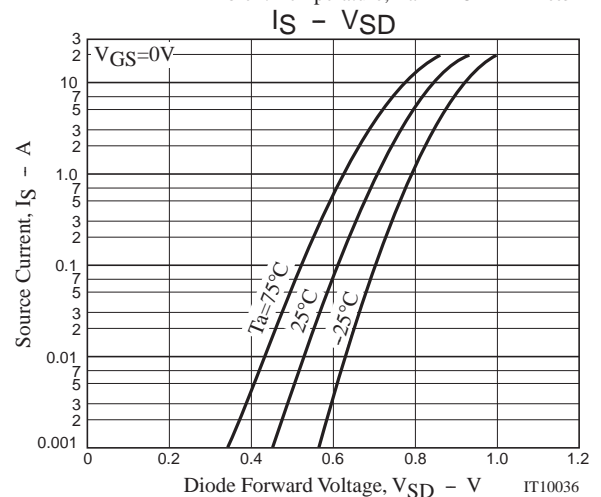
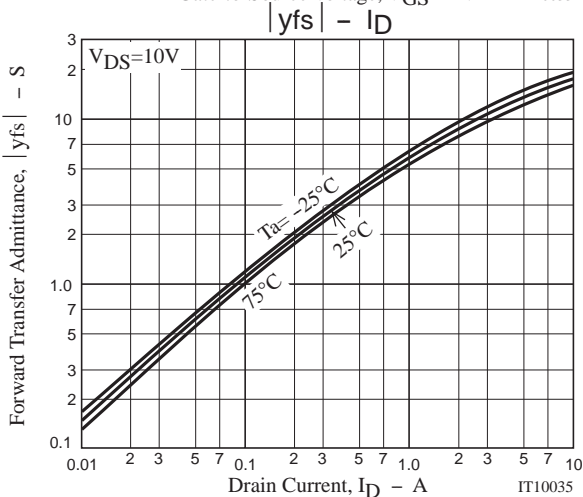
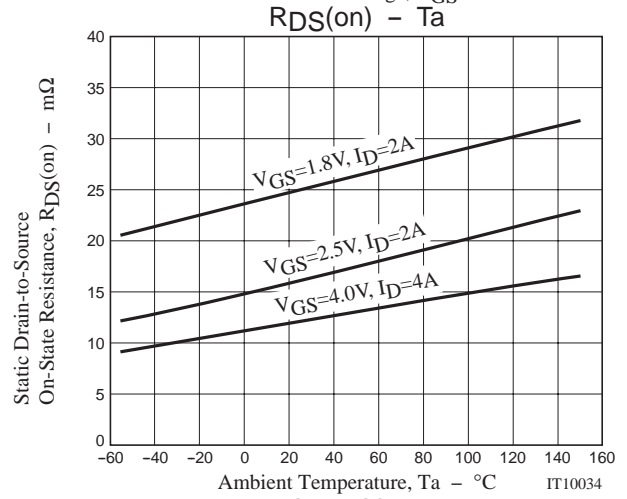
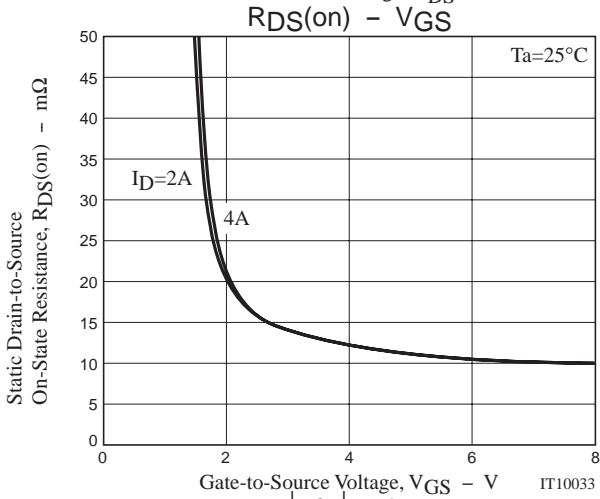
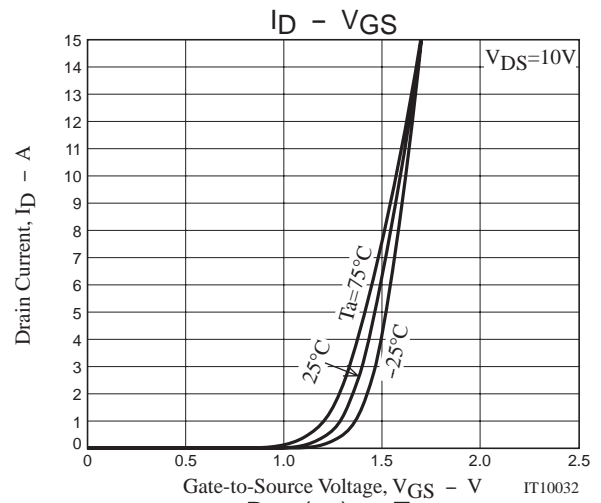
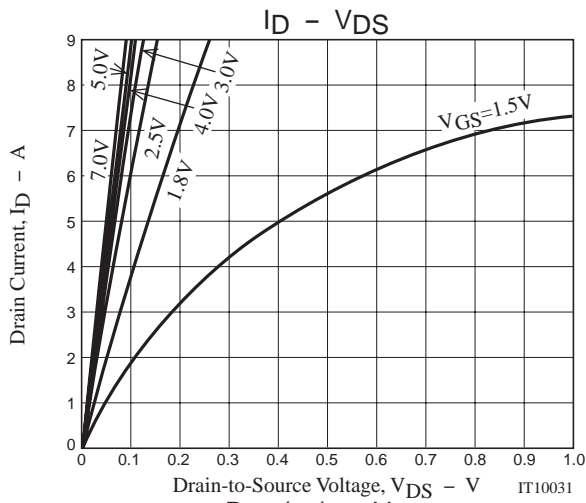
Electrical Connection



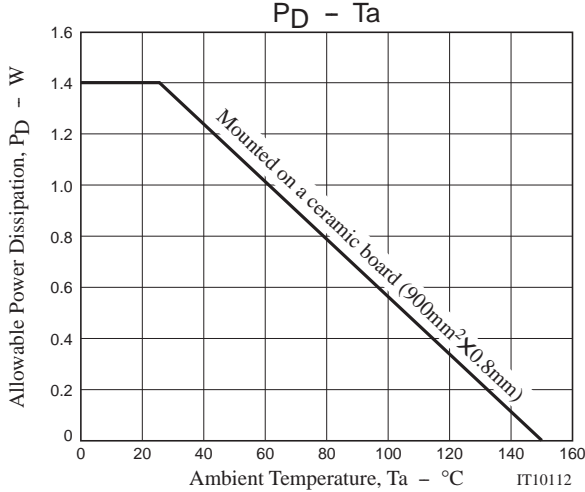
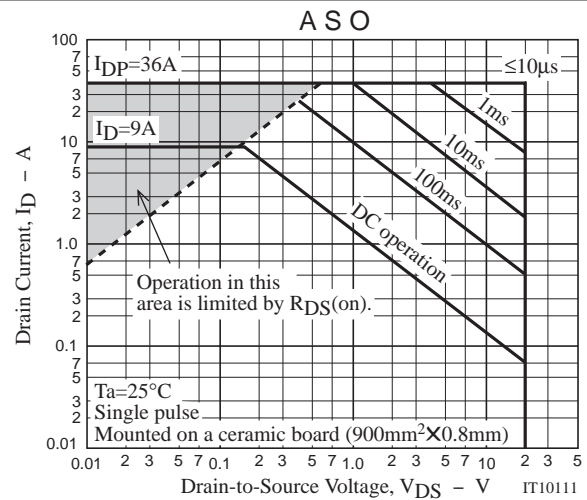
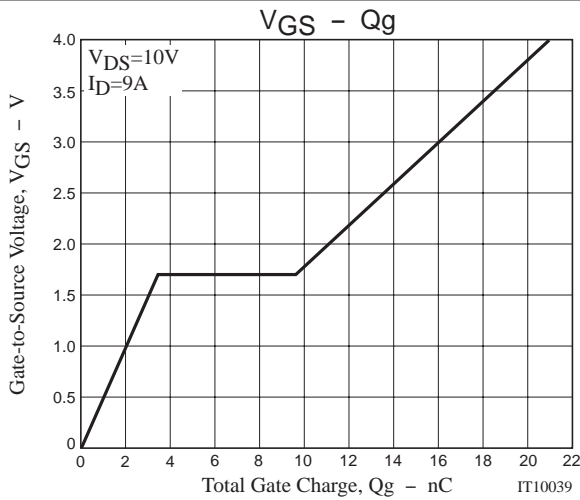
Switching Time Test Circuit



ECH8411



ECH8411



Note on usage : Since the ECH8411 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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